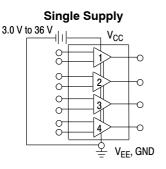
Single Supply Quad Operational Amplifiers

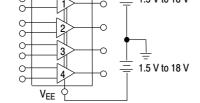
The MC3403 is a low cost, quad operational amplifier with true differential inputs. The device has electrical characteristics similar to the popular MC1741C. However, the MC3403 has several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 36 V with quiescent currents about one third of those associated with the MC1741C (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

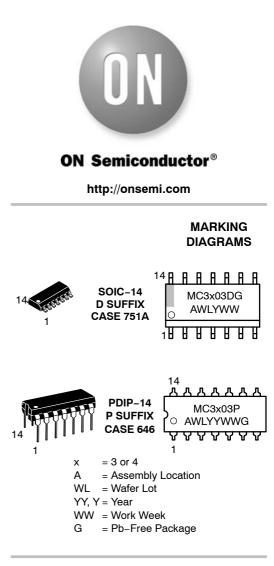
Features

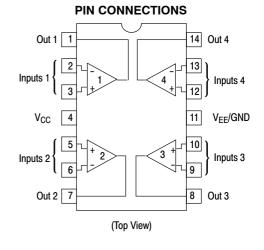
- Short Circuit Protected Outputs
- Class AB Output Stage for Minimal Crossover Distortion
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 36 V
- Split Supply Operation: ±1.5 V to ±18 V
- Low Input Bias Currents: 500 nA Max
- Four Amplifiers Per Package
- Internally Compensated
- Similar Performance to Popular MC1741C
- Industry Standard Pin-outs
- ESD Diodes Added for Increased Ruggedness
- Pb-Free Packages are Available



Split Supplies V_{CC} = 1.5 V to 18 V







ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC3303D	SOIC-14	
MC3303DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC3303DR2	SOIC-14	
MC3303DR2G	SOIC-14 (Pb-Free)	2500 Tape & Reel
MC3303P	PDIP-14	
MC3303PG	PDIP-14 (Pb-Free)	25 Units / Rail
MC3403D	SOIC-14	
MC3403DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC3403DR2	SOIC-14	
MC3403DR2G	SOIC-14 (Pb-Free)	2500 Tape & Reel
MC3403P	PDIP-14	
MC3403PG	PDIP-14 (Pb-Free)	25 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltages Single Supply Split Supplies	V _{CC} V _{CC} , V _{EE}	36 ±18	Vdc
Input Differential Voltage Range (Note 1)	V _{IDR}	±36	Vdc
Input Common Mode Voltage Range (Notes 1 and 2)	V _{ICR}	±18	Vdc
Storage Temperature Range	T _{stg}	–55 to +125	°C
Operating Ambient Temperature Range MC3303 MC3403	T _A	-40 to +85 0 to +70	°C
Junction Temperature	TJ	150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Split power supplies.

2. For supply voltages less than \pm 18 V, the absolute maximum input voltage is equal to the supply voltage.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +15 \text{ V}, V_{EE} = -15 \text{ V} \text{ for MC3403}; V_{CC} = +14 \text{ V}, V_{EE} = GND \text{ for MC3303 T}_{A} = 25^{\circ}C$, unless otherwise noted.)

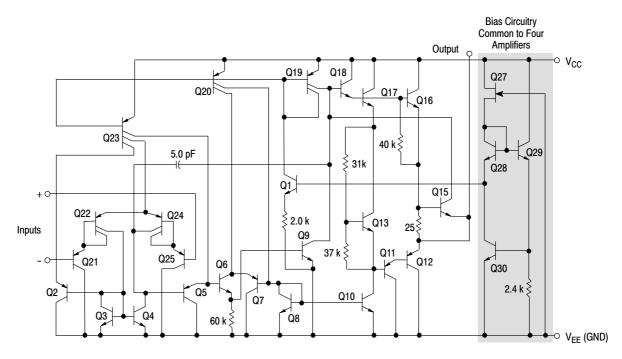
			MC3403			MC3303		
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Мах	Unit
Input Offset Voltage T _A = T _{high} to T _{low} (Note 3)	V _{IO}	- -	2.0 _	10 12		2.0 -	8.0 10	mV
Input Offset Current $T_A = T_{high}$ to T_{low}	I _{IO}		30 -	50 200		30 -	75 250	nA
Large Signal Open Loop Voltage Gain $V_O = \pm 10 V$, $R_L = 2.0 k\Omega$ $T_A = T_{high}$ to T_{low}	A _{VOL}	20 15	200 -		20 15	200 -		V/mV
Input Bias Current $T_A = T_{high}$ to T_{low}	I _{IB}		-200 -	-500 -800		-200 -	-500 -1000	nA
Output Impedance f = 20 Hz	z _o	-	75	-	-	75	-	Ω
Input Impedance f = 20 Hz	z _i	0.3	1.0	-	0.3	1.0	-	MΩ
Output Voltage Range $R_L = 10 \ k\Omega$ $R_L = 2.0 \ k\Omega$ $R_L = 2.0 \ k\Omega$, $T_A = T_{high}$ to T_{low}	Vo	±12 ±10 ±10	±13.5 ±13 –	- - -	12 10 10	12.5 12 -	- - -	V
Input Common Mode Voltage Range	V _{ICR}	+13 V -V _{EE}	+13 V -V _{EE}	-	+12 V -V _{EE}	+12.5 V -V _{EE}	-	V
Common Mode Rejection $R_S \leq$ 10 $k\Omega$	CMR	70	90	-	70	90	-	dB
Power Supply Current (V _O = 0) $R_L = \infty$	I_{CC}, I_{EE}	-	2.8	7.0	-	2.8	7.0	mA
Individual Output Short-Circuit Current (Note 4)	I _{SC}	±10	±20	±45	±10	±30	±45	mA
Positive Power Supply Rejection Ratio	PSRR+	-	30	150	-	30	150	μV/V
Negative Power Supply Rejection Ratio	PSRR-	-	30	150	-	30	150	μV/V
Average Temperature Coefficient of Input Offset Current $T_A = T_{high}$ to T_{low}	$\Delta I_{IO} / \Delta T$	_	50	_	_	50	_	pA/°C
Average Temperature Coefficient of Input Offset Voltage $T_A = T_{high} \text{ to } T_{low}$	$\Delta V_{IO} / \Delta T$	-	10	-	-	10	-	μV/°C
Power Bandwidth A_V = 1, R_L = 10 k Ω , V_O = 20 V(p–p), THD = 5%	BWp	-	9.0	_	-	9.0	_	kHz
Small–Signal Bandwidth $A_V = 1, R_L = 10 \text{ k}\Omega, V_O = 50 \text{ mV}$	BW	-	1.0	_	_	1.0	_	MHz
Slew Rate $A_V = 1$, $V_i = -10$ V to $+10$ V	SR	_	0.6	-	-	0.6	-	V/μs
Rise Time A _V = 1, R _L = 10 k Ω , V _O = 50 mV	t _{TLH}	-	0.35	-	-	0.35	-	μs
Fall Time A _V = 1, R _L = 10 k Ω , V _O = 50 mV	t _{TLH}	-	0.35	-	-	0.35	-	μs
Overshoot A _V = 1, R _L = 10 k Ω , V _O = 50 mV	os	_	20	-	-	20	-	%
Phase Margin A _V = 1, R _L = 2.0 kΩ, V _O = 200 pF	φm	_	60	-	-	60	-	0
Crossover Distortion (V _{in} = 30 mVpp,V _{out} = 2.0 Vpp, f = 10 kHz)	-	-	1.0	-	-	1.0	-	%

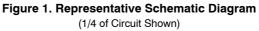
3. MC3303: $T_{low} = -40^{\circ}C$, $T_{high} = +85^{\circ}C$, MC3403: $T_{low} = 0^{\circ}C$, $T_{high} = +70^{\circ}C$ 4. Not to exceed maximum package power dissipation.

		MC3403			MC3303			
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	-	2.0	10	-	-	10	mV
Input Offset Current	I _{IO}	-	30	50	-	-	75	nA
Input Bias Current	I _{IB}	-	-200	-500	-	-	-500	nA
Large Signal Open Loop Voltage Gain $R_L = 2.0 \ k\Omega$	A _{VOL}	10	200	-	10	200	-	۷/m۱
Power Supply Rejection Ratio	PSRR	-	-	150	-	-	150	μV/\
Output Voltage Range (Note 5) $R_L = 10 \text{ k}\Omega, V_{CC} = 5.0 \text{ V}$ $R_L = 10 \text{ k}\Omega, 5.0 \le V_{CC} \le 30 \text{ V}$	V _{OR}	3.3 V _{CC} -2.0	3.5 V _{CC} -1.7		3.3 V _{CC} -2.0	3.5 V _{CC} -1.7	-	V _{pp}
Power Supply Current	I _{CC}	-	2.5	7.0	-	2.5	7.0	mA
Channel Separation f = 1.0 kHz to 20 kHz (Input Referenced)	CS	-	-120	-	-	-120	-	dB

ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V, V_{EE} = GND, T_A = 25°C, unless otherwise noted.)

5. Output will swing to ground with a 10 k Ω pull down resistor.





CIRCUIT DESCRIPTION

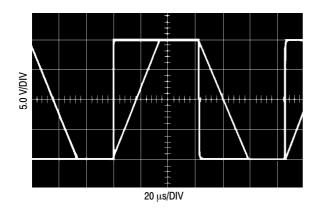
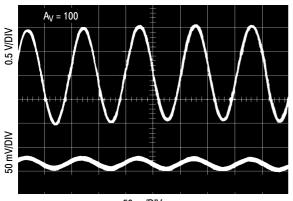


Figure 2. Inverter Pulse Response

The MC3403/3303 is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input device Q24 and Q22 with input buffer transistors Q25 and Q21 and the differential to single ended converter Q3 and Q4. The first



50 μs/DIV

Figure 3. Sine Wave Response

stage performs not only the first stage gain function but also performs the level shifting and Transconductance reduction functions. By reducing the Transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The Transconductance reduction is accomplished by splitting the collectors of Q24 and Q22. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single–ended converter. The

amplifier stage. The output stage is unique because it allows the output to swing to ground in single supply operation and yet does not exhibit any crossover distortion in split supply operation. This is possible because Class AB operation is utilized.

second stage consists of a standard current source load

Each amplifier is biased from an internal voltage regulator which has a low temperature coefficient, thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

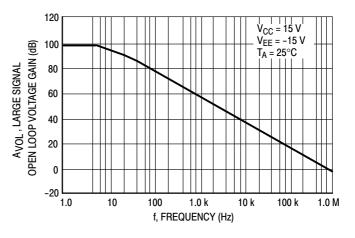


Figure 4. Open Loop Frequency Response

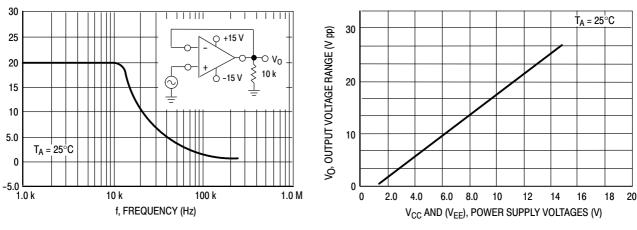
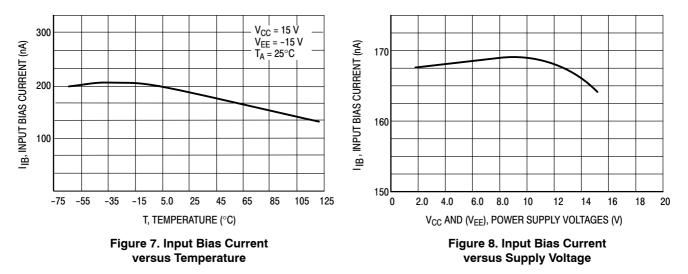


Figure 5. Power Bandwidth

Figure 6. Output Swing versus Supply Voltage

VO, OUTPUT VOLTAGE (Vpp)



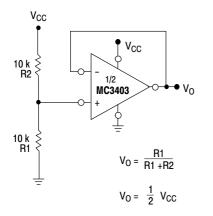
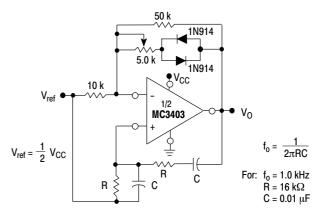
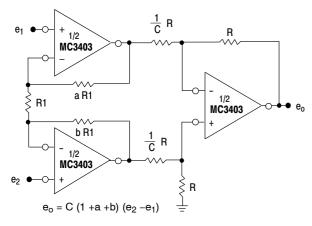
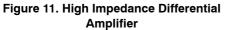


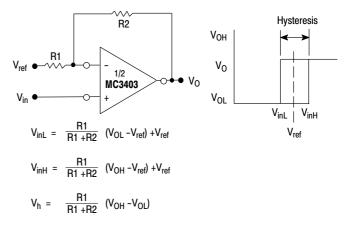
Figure 9. Voltage Reference



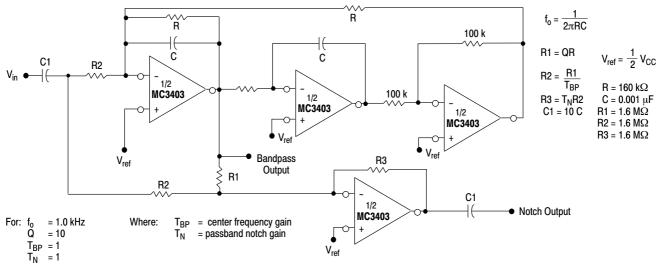














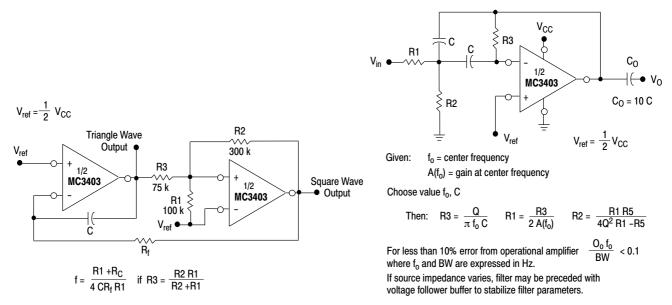
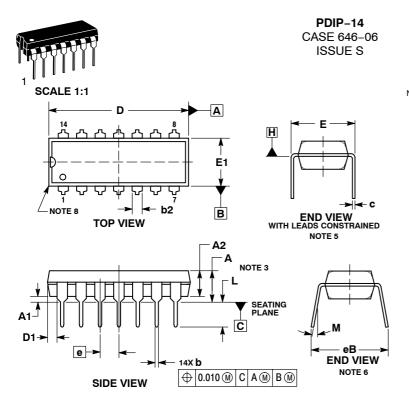




Figure 15. Multiple Feedback Bandpass Filter



STYLES ON PAGE 2



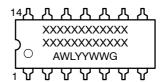
DATE 22 APR 2015

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
- З.
- DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE 4
- NOT TO EXCEED 0.10 INCH. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM 5 PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
- DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE 7.
- LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE 8. CORNERS).

	INC	INCHES MILLIME		ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060) TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
Е	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54 BSC	
eВ		0.430		10.92
L	0.115	0.150	2.92	3.81
М		10°		10°

GENERIC **MARKING DIAGRAM***



XXXXX = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- YY = Year

А

G

- ww = Work Week
 - = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

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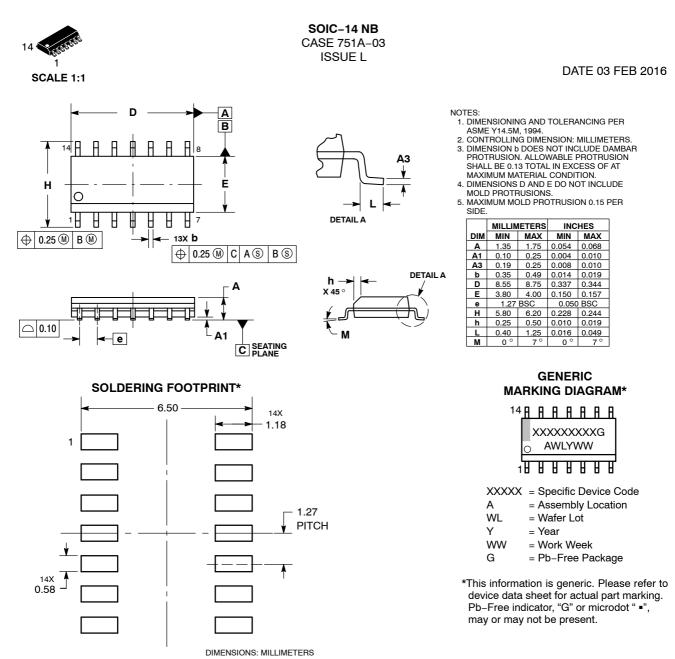
PDIP-14 CASE 646-06 ISSUE S

DATE 22 APR 2015

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. DRAIN 2. SOURCE 3. GATE 4. NO CONNECTION 5. GATE 6. SOURCE 7. DRAIN 8. DRAIN 9. SOURCE 10. GATE 11. NO CONNECTION 12. GATE 13. SOURCE 14. DRAIN
STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. NO CONNECTION 5. SOURCE 6. DRAIN 7. GATE 8. GATE 9. DRAIN 10. SOURCE 11. NO CONNECTION 12. SOURCE 13. DRAIN 14. GATE	STYLE 6: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 7: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 8: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
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*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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